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**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

Complete if Kn wnSheet 1 of 2

Application Number	
Filing Date	
First Named Inventor	Onishi
Art Unit	
Examiner Name	
Attorney Docket Number	SO-1

U. S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
	1	US- 4,515,675	05/07/1985	Kieser et al	
	2	US- 5,482,611	01/09/1996	Helmer et al	
	3	US- 5,512,150	04/30/1996	Bourez et al	
	4	US- 5,597,459	01/28/1997	Altshuler	
	5	US- 5,685,959	11/11/1997	Bourez et al	
	6	US- 5,865,961	02/02/1999	Yokoyama et al	
	7	US- 6,159,351	12/12/2000	J'Afer et al	
	8	US- 6,251,242 B1	06/26/2001	Fu et al	
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FOREIGN PATENT DOCUMENTS						
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		Filing Date	
		First Named Inventor	Onishi
		Art Unit	
		Examiner Name	
Sheet 2 of 2	Attorney Docket Number	SO-1	

NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
	1	Ohnishi et al, Chemical Vapor Deposition of Single-Crystalline ZnO Film with Smooth Surface on Intermediately Sputtered ZnO Thin Film on Sapphire, Japanese Journ. of App. Physics, vol. 17, no. 5, May 1978, pp. 773-778	
	2	Onishi et al, Transparent and Highly Oriented ZnO films Grown at Low Temperature by Sputtering with a Modified Sputter Gun, Applied Phys. Letters, vol. 38 no. 6 March 1981	

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